Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	polymer near3 movable adj elctrode and mems	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:04
L2	0	polymer same movable adj elctrode and mems	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:04
L3	7028	movable adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:05
L4	301	movable adj electrode and polymer	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:06
L5	40	movable adj electrode and polymer same support	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:06
L6	10	movable adj electrode and polymer same support and mems	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:06
S1	1	("20050078348").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:03
S2	1	("5835255").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 14:32
S3	673297	cavity cavities	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 10:49
S4	132749	electrode and second near2 electrode	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 10:50
S5	352272	spacer supporter standoff	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 10:50
S6	1969	S3 and S4 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 10:55

<b>S7</b>	650	S6 and display	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:08
S8	1729	cmos same mems	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:09
S9	776	S3 and S8	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:10
S10	177664	sidewall	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:10
S11	181	S9 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:17
S12	402592	ito indium adj tin adj oxide	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:12
S13	303	cmos bond\$3 mems	US-PGPUB; USPAT; USOCR; EPO; JPO	SAME	OFF	2006/01/26 12:55
S22	46	cmos and mems and movable adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO	SAME	OFF	2006/01/26 12:59
S23	11118	sidewall same spacer	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 12:59
S24	902	S23 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 13:03
S26	7028	movable adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/27 15:05
S27	2	S24 and S26	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 13:02

S28	43	("2534846"   "3439973"   "3443854"   "3653741"   "3813265"   "3955880"   "4099854"   "4228437"   "4377324"   "4389096"   "4403248"   "4445050"   "4519676"   "4531126"   "4663083"   "4681403"   "4748366"   "4790635"   "4982184"   "5022745"   "5044736"   "5075796"   "5124834"   "5153771"   "5168406"   "5231532"   "5233459"   "5311360"   "5381253"   "5401983"   "5459610"   "5497172"   "5500635"   "5500761"   "5579149"   "5619059"   "5636052"   "5710656").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:17
S29	14	("5710656").URPN.	USPAT	OR	OFF	2006/01/26 13:22
S30	103	("2534846"   "3439973"   "3443854"   "3653741"   "3656836"   "3813265"   "3955880"   "4099854"   "4228437"   "4377324"   "4389096"   "4403248"   "4445050"   "4519676"   "4531126"   "47663083"   "4681403"   "4748366"   "4786128"   "4790635"   "4982184"   "5022745"   "5044736"   "5078479"   "5124834"   "5153771"   "5168406"   "5231532"   "5233459"   "5311360"   "5401983"   "5459610"   "5497172"   "5579149"   "5619059"   "5636052"   "5710656"   "5739945"   "5784190"   "5825528"   "5835255").PN. OR ("5986796"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:24
S31	1	S30 and sidewall	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:25
532	16	moveable adj electrode and stack	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:28
S33	14	"6097092"	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:33
S34	28	freestanding near3 (stack gate)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:35
S35	5	lcd and S23 and stack	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:36

S36	9	freestanding near3 gate	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 13:37
S37	12	interference near1 display near1 cell	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2006/01/26 14:32
S38	2	("5835255"   "6448709").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:15
S39	31623	micro electro mechanical system or mems	US-PGPUB; USPAT; USOCR	ADJ	OFF	2006/01/26 15:16
S40	0	S39 same (gate stack cmos mosfet) and sidwall same spacer	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:17
S41	0	S39 same sidwall same spacer	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:17
S42	7	S39 same sidewall same spacer	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:23
S43	4	release adj layer and S39 and sidewall same spacer	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:26
S44	1464	spacer near5 sidewall near5 electrode	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 15:27
S45	3	S39 and S44	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 17:02
S46	0	polysilicon near2 support same S26	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 17:29
S47	111	polysilicon same S26	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 17:02
S48	1	paraffin same S26	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 17:31
S49	217	macromolecule polymer	US-PGPUB; USPAT; USOCR	ADJ	OFF	2006/01/26 17:31
S50	1	S49 and S26	US-PGPUB; USPAT; USOCR	ADJ	OFF	2006/01/26 17:31
S51	. 21	paraffin and S26	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/26 17:31